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SDM1100LP

#### **1A SCHOTTKY BARRIER RECTIFIER**

### **Product Summary**

V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F(MAX)</sub> (V) @ +25°C	I <sub>R(MAX)</sub> (μΑ) @ +25°C
100	1	0.77	0.35

#### **Features and Benefits**

- Guard Ring Die Construction Transient Protection
- Low Power Loss. High Efficiency
- Reduced ultra-low forward voltage drop (V<sub>F</sub>); Better efficiency and cooler operation.
- Reduced high temperature reverse leakage and increased reliability against thermal runaway failure in high temperature operation.
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Description and Applications**

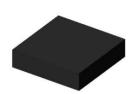
The Schottky Barrier Rectifier is designed with low  $V_F$  and low reverse leakage in the low profile U-DFN2020-2 (Type B) package. It is ideal for use as a rectifier, freewheel diode or blocking diode in applications such as:

- Blocking Diode
- Boost Diode
- Recirculating Diode

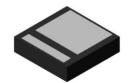
#### **Mechanical Data**

- Case: U-DFN2020-2 (Type B)
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208 (3)
- Polarity: See Below
- Weight: 6.757mg (Approximate)

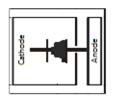
#### U-DFN2020-2 (Type B)







**Bottom View** 



Top View Internal Schematic

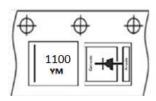
### **Ordering Information** (Note 4)

Part Number	Case	Packaging
SDM1100LP-7	U-DFN2020-2 (Type B)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information





1100 = Product Type Marking Code
YM = Date Code Marking
Y = Year (av. D = 2016)

Y = Year (ex: D = 2016) M = Month (ex: 6 = June) Bar = Cathode

Date Code Kev

Year	2014	20	015	2016	2017	20	18	2019	2020	20	21	2022
Code	В		С	D	E		=	G	Н		l	J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	100	<b>&gt;</b>
Average Rectified Output Current	Io	1	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	40	Α

### **Thermal Characteristics**

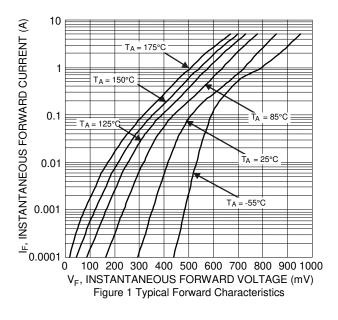
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 5)	R <sub>eJC</sub>	16	°C/W
Typical Thermal Resistance Junction to Ambient (Note 5)	R <sub>0JA</sub>	65	°C/W
Operating Temperature Range	TJ	-55 to +175	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +175	°C

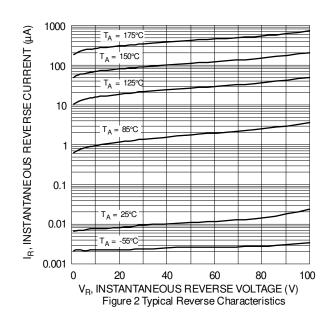
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage	$V_{(BR)R}$	100	_		V	I <sub>R</sub> =1mA
	V <sub>F</sub>	_	_	0.77		$I_F = 1A, T_J = +25^{\circ}C$
Forward Voltage (Note 6)		_	0.58	0.62	v	$I_F = 1A, T_J = +125^{\circ}C$
Forward Voltage (Note 6)		_	_	0.86	V	I <sub>F</sub> = 2A, T <sub>J</sub> = +25°C
		_	0.65	0.70		$I_F = 2A, T_J = +125^{\circ}C$
	IR	_	_	0.1	μΑ	$V_R = 50V, T_J = +25^{\circ}C$
Lookogo Current (Noto 6)		_	_	0.015	mA	$V_R = 50V, T_J = +85^{\circ}C$
Leakage Current (Note 6)		_	_	0.35	μΑ	V <sub>R</sub> = 100V, T <sub>J</sub> = +25°C
		_	_	0.35	mA	V <sub>R</sub> = 100V, T <sub>J</sub> = +125°C
Total Capacitance	C <sub>T</sub>	_	40	_	pF	$V_R = 5V, f = 1MHz$

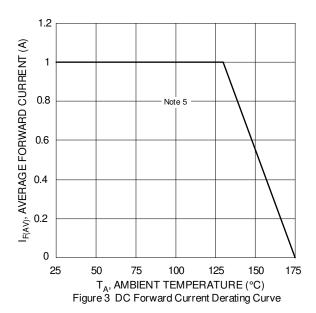
Notes:

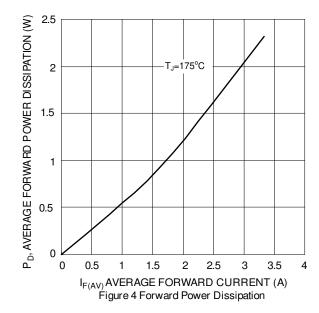
- 5. Device mounted 1inch sq. copper pad, 2oz.
- 6. Short duration pulse test used to minimize self-heating effect.

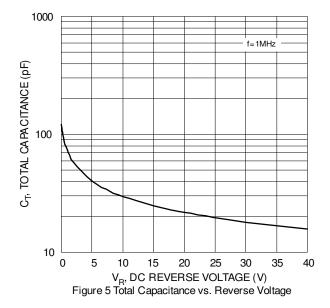








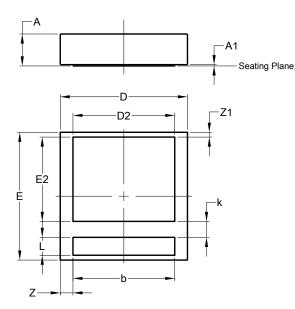






### **Package Outline Dimensions**

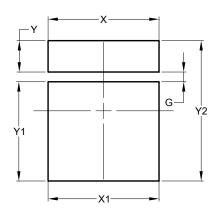
Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-2 (Type B)						
Dim	Min Max Typ					
Α	0.47	0.53	0.50			
A1	0.00	0.05	0.02			
b	1.55	1.65	1.60			
D	1.95 2.05 2.00					
D2	1.50 1.70 1.60					
Е	1.95	2.05	2.00			
E2	1.22	1.42	1.32			
k	0.25 BSC					
L	0.23	0.33	0.28			
Z	0.20 BSC					
Z1	0.075 BSC					
All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
G	0.150
Х	1.700
X1	1.700
Υ	0.480
Y1	1.520
Y2	2.150



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